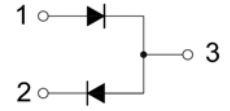


Features

- For general purpose switching applications
- Fast switching speed
- High conductance



SOT-523



Schematic Diagram

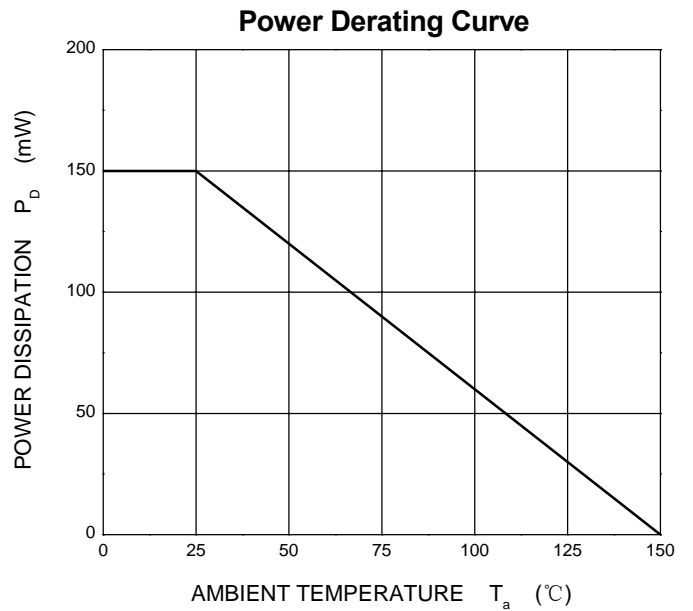
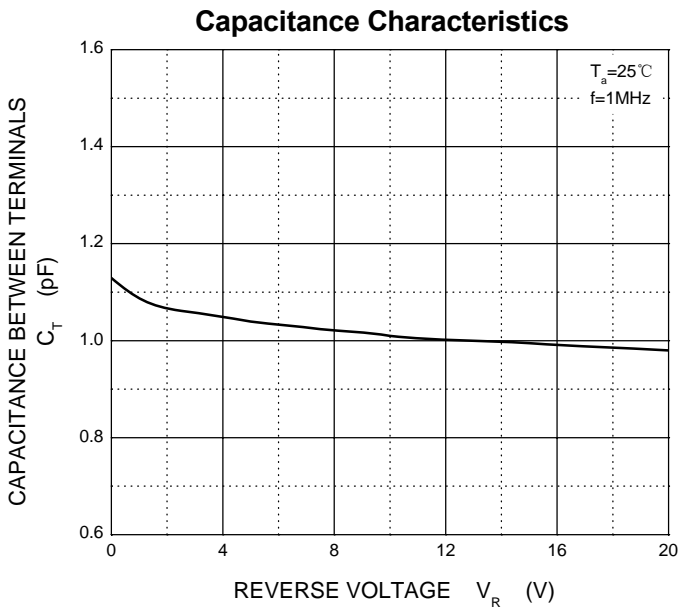
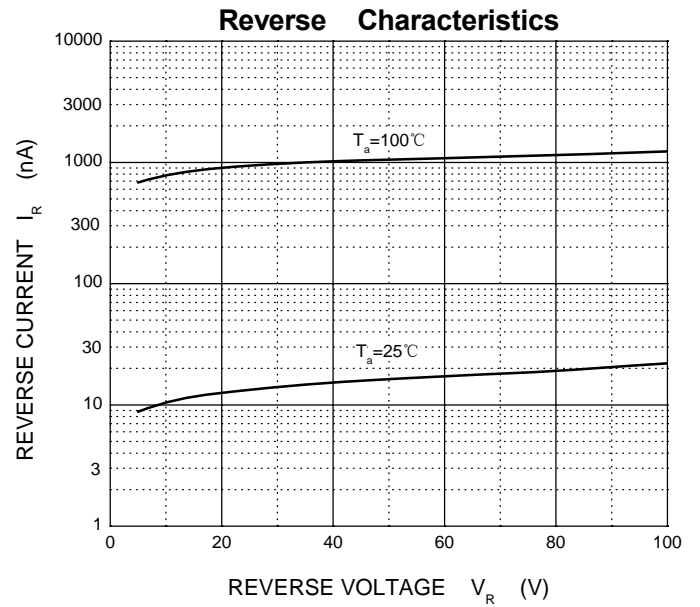
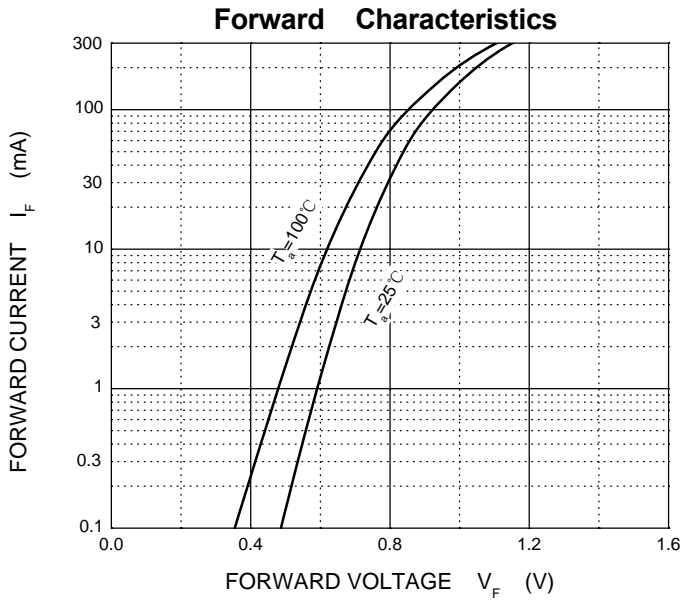
Absolute Maximum Ratings (T_A=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Reverse Voltage	V _R	85	V
Forward Current	I _F	75	mA
Non-Repetitive Peak Forward Surge Current@t=8.3ms	I _{FSM}	2.0	A
Power Dissipation	P _D	150	mW
Thermal Resistance Junction to Ambient	R _{θJA}	833	°C/W
Junction Temperature	T _J	150	°C
Storage Temperature range	T _{STG}	-55 to +150	°C

Electrical Characteristics (T_A=25°C unless otherwise noted)

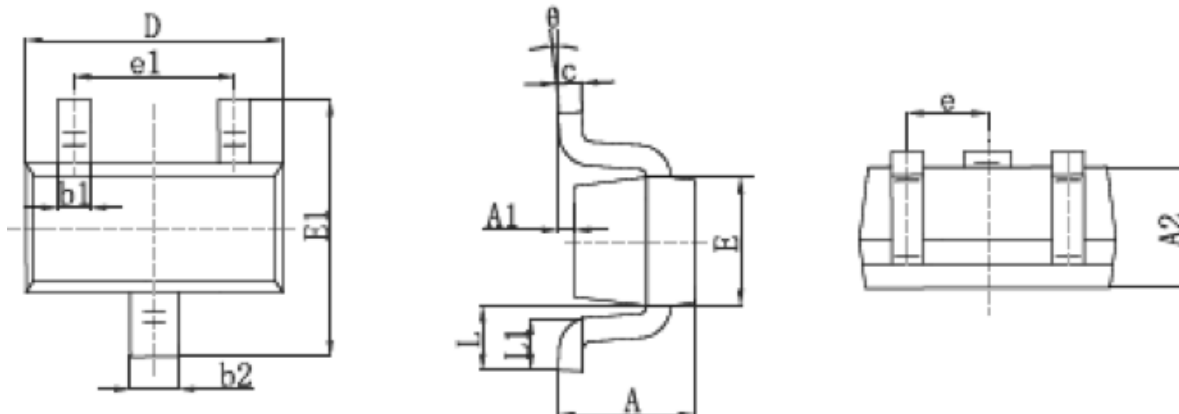
Parameter	Symbol	Test conditions	Min	Max	Unit
Reverse Breakdown Voltage	V _(BR)	I _R = 1μA	85	-	V
Reverse Voltage Leakage Current	I _{R1}	V _R =75V	-	2	μA
	I _{R2}	V _R =25V	-	0.03	μA
Forward Voltage	V _F	I _F =1mA I _F =10mA I _F =50mA I _F =150mA	-	715 855 1000 1250	mV
Diode Capacitance	C _D	V _R =0 f=1MHz	-	1.5	pF
Reverse Recovery Time	t _{rr}	I _F =I _R =10mA I _{rr} =0.1×I _R , R _L =100Ω	-	4	ns

Typical Electrical Characteristic Curves



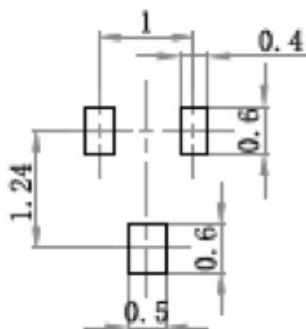
Package Outline Dimensions

SOT-523



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.700	0.900	0.028	0.035
A1	0.000	0.100	0.000	0.004
A2	0.700	0.800	0.028	0.031
b1	0.150	0.250	0.006	0.010
b2	0.250	0.350	0.010	0.014
c	0.100	0.200	0.004	0.008
D	1.500	1.700	0.059	0.067
E	0.700	0.900	0.028	0.035
E1	1.450	1.750	0.057	0.069
e	0.500 TYP.		0.020 TYP.	
e1	0.900	1.100	0.035	0.043
L	0.400 REF.		0.016 REF.	
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°

Suggested Pad Layout



- Note:
1. Controlling dimension: in millimeters.
 2. General tolerance: ±0.05mm.
 3. The pad layout is for reference purposes only.

Order Information

Device	Package	Marking	Quantity	HSF Status
GSBAV99T	SOT-523	JE	3000pcs / Reel	RoHS Compliant/HF